General Description

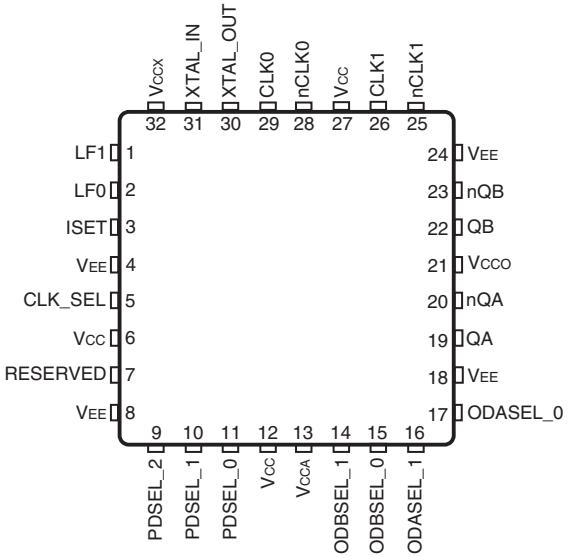
The ICS813N322-02 device uses IDT's fourth generation FemtoClock® NG technology for optimal high clock frequency and low phase noise performance, combined with a low power consumption and high power supply noise rejection. The ICS813N322-02 is a PLL based synchronous multiplier that is optimized for Ethernet to SONET/PDH clock jitter attenuation and frequency translation.

The ICS813N322-02 is a fully integrated Phase Locked loop utilizing a FemtoClock NG Digital VCXO that provides the low jitter, high frequency SONET/PDH output clock that easily meets OC-48 jitter requirements. This VCXO technology simplifies PLL design by replacing the pullable crystal requirement of analog VCXOs with a fixed 27MHz generator crystal. Jitter attenuation down to 10Hz is provided by an external loop filter. Pre-divider and output divider multiplication ratios are selected using device selection control pins. The multiplication ratios are optimized to support most common clock rates used in PDH, SONET and Ethernet applications. The device requires the use of an external, inexpensive fundamental mode 27MHz crystal. The device is packaged in a space-saving 32-VFQFN package and supports industrial temperature range.

Features

- Fourth Generation FemtoClock® NG technology
- Two LVPECL output pairs
- Each output supports independent frequency selection at 19.44MHz, 77.76MHz, 155.52MHz and 622.08MHz
- Two differential inputs support the following input types: LVPECL, LVDS, LVHSTL, HCSL
- Accepts input frequencies from 8kHz to 156.25MHz including 8kHz,19.44MHz, 25MHz, 62.5MHz, 77.76MHz, 125MHz, 155.52MHz and 156.25MHz
- Crystal interface designed for a 27MHz, 10pF parallel resonant crystal
- Attenuates the phase jitter of the input clock by using a low-cost fundamental mode crystal
- Customized settings for jitter attenuation and reference tracking using an external loop filter connection
- FemtoClock NG frequency multiplier provides low jitter, high frequency output
- Absolute pull range: ±50ppm
- Power supply noise rejection (PSNR): -95dB (typical)
- FemtoClock NG VCXO frequency: 2488.32MHz
- RMS phase jitter @ 155.52MHz, using a 27MHz crystal (12kHz – 20MHz): 0.674ps (typical)
- 3.3V supply voltage
- 0°C to 70°C ambient operating temperature
- Available in lead-free (RoHS 6) package

Pin Assignment



ICS813N322-02

32 Lead VFQFN

5mm x 5mm x 0.925mm package body

K Package

Top View

Block Diagram

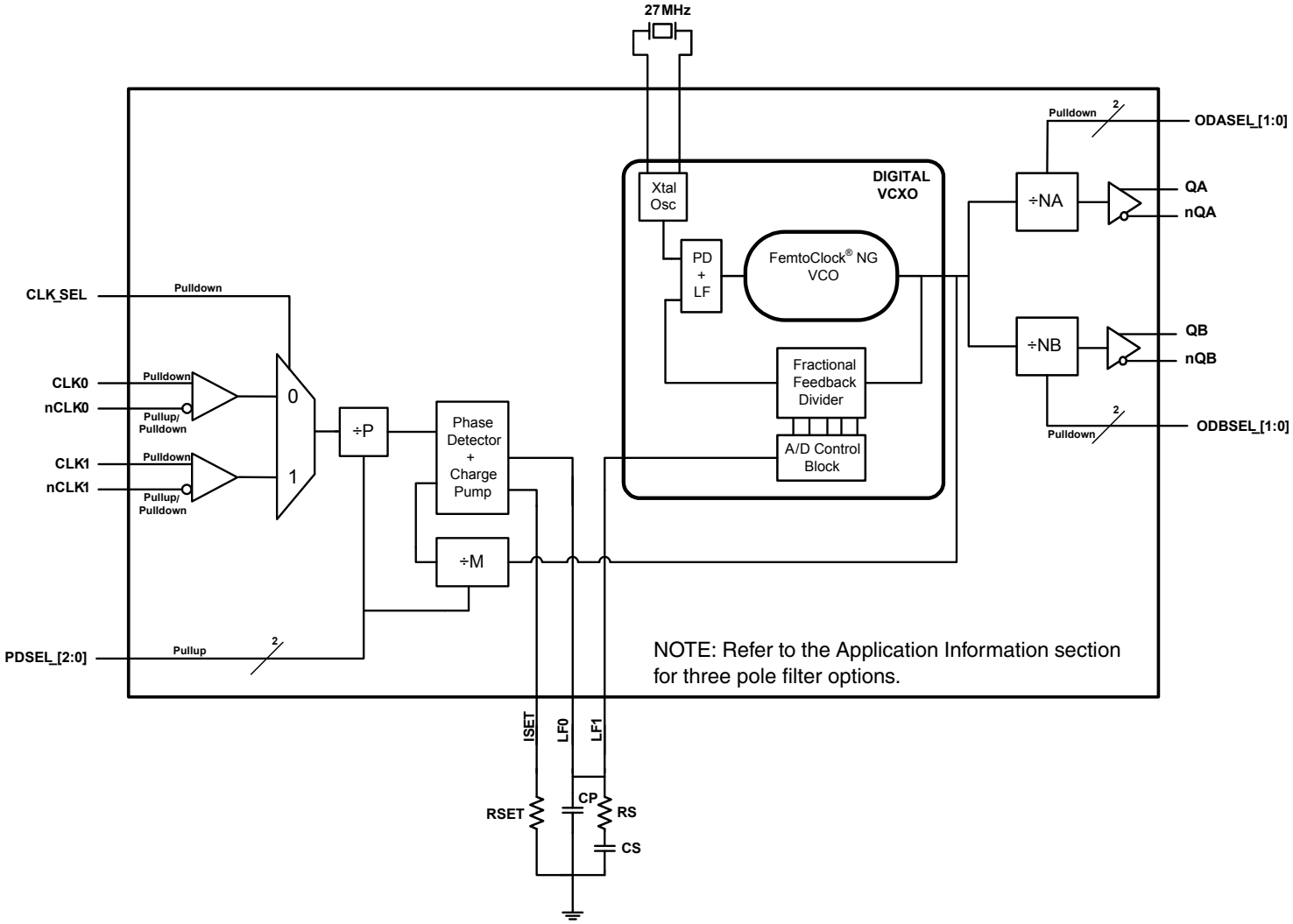


Table 1. Pin Descriptions

Number	Name	Type		Description
1, 2	LF1, LF0	Analog Input/Output		Loop filter connection node pins. LF0 is the output. LF1 is the input.
3	ISET	Analog Input/Output		Charge pump current setting pin.
4, 8, 18, 24	V_{EE}	Power		Negative supply pins.
5	CLK_SEL	Input	Pulldown	Input clock select. When HIGH selects CLK1, nCLK1. When LOW, selects CLK0, nCLK0. LVCMOS / LVTTL interface levels.
6, 12, 27	V_{CC}	Power		Core supply pins.
7	RESERVED	Reserve		Reserve pin.
9, 10, 11	PDSEL_2, PDSEL_1, PDSEL_0	Input	Pullup	Pre-divider select pins. LVCMOS/LVTTL interface levels. See Table 3A.
13	V_{CCA}	Power		Analog supply pin.
14, 15	ODBSEL_1, ODBSEL_0	Input	Pulldown	Frequency select pins for Bank B output. See Table 3B. LVCMOS/LVTTL interface levels.
16, 17	ODASEL_1, ODASEL_0	Input	Pulldown	Frequency select pins for Bank A output. See Table 3B. LVCMOS/LVTTL interface levels.
19, 20	QA, nQA	Output		Differential Bank A clock outputs. LVPECL interface levels.
21	V_{CCO}	Power		Output supply pin.
22, 23	QB, nQB	Output		Differential Bank B clock outputs. LVPECL interface levels.
25	nCLK1	Input	Pullup/ Pulldown	Inverting differential clock input. $V_{CC}/2$ bias voltage when left floating.
26	CLK1	Input	Pulldown	Non-inverting differential clock input.
28	nCLK0	Input	Pullup/ Pulldown	Inverting differential clock input. $V_{CC}/2$ bias voltage when left floating.
29	CLK0	Input	Pulldown	Non-inverting differential clock input.
30, 31	XTAL_OUT, XTAL_IN	Input		Crystal oscillator interface. XTAL_IN is the input. XTAL_OUT is the output.
32	V_{CCX}	Power		Power supply pin for the crystal oscillator.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics,* for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			3.5		pF
R_{PULLUP}	Input Pullup Resistor			51		kΩ
$R_{PULLDOWN}$	Input Pulldown Resistor			51		kΩ

Function Tables

Table 3A. Pre-Divider Selection Function Table

Inputs			
PDSEL_2	PDSEL_1	PDSEL_0	÷P Value
0	0	0	1
0	0	1	1944
0	1	0	2500
0	1	1	6250
1	0	0	7776
1	0	1	12500
1	1	0	15552
1	1	1	15625 (default)

Table 3B. Output Divider Function Table

Inputs		
ODxSEL_1	ODxSEL_0	÷Nx Value
0	0	128 (default)
0	1	32
1	0	16
1	1	4

NOTE: x denotes A or B.

Table 3C. Example Configurations for Selected Output and Input Frequencies

User Configuration and Frequencies				Internal Divider Values and Frequencies				
Input Frequency (MHz)	Output Frequency (MHz)	PDSEL_ [2:0]	ODxSEL_ [1:0]	Pre-Divider P	Feedback Divider M	Fractional Feedback Divider FemtoClock NG	FemtoClock NG VCXO Center Frequency (MHz)	Output Divider Nx
0.008	19.44	000	00	1	128	2430	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
19.44	19.44	001	00	1944	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
25	19.44	010	00	2500	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
62.5	19.44	011	00	6250	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
77.76	19.44	100	00	7776	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
125	19.44	101	00	12500	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
155.52	19.44	110	00	15552	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4
156.25	19.44	111	00	15625	128	1944	2488.32	128
	77.76		01					32
	155.52		10					16
	622.08		11					4

NOTE: ODxSEL denotes ODASEL or ODBSEL.

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{CC}	3.63V
Inputs, V_I XTAL_IN Other Inputs	 0V to 2V -0.5V to V_{CC}+ 0.5V
Outputs, I_O Continuous Current Surge Current	 50mA 100mA
Package Thermal Impedance, θ_{JA}	33.1°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. LVPECL Power Supply DC Characteristics, $V_{CC} = V_{CCO} = V_{CCX} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = 0°C$ to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{CC}	Core Supply Voltage		3.135	3.3	3.465	V
V_{CCA}	Analog Supply Voltage		V_{CC} – 0.30	3.3	V_{CC}	V
V_{CCO}	Output Supply Voltage		3.135	3.3	3.465	V
V_{CCX}	Charge Pump Supply Voltage		3.135	3.3	3.465	V
I_{EE}	Power Supply Current				274	mA
I_{CCA}	Analog Supply Current				30	mA

Table 4B. LVCMOS/LVTTL DC Characteristics, $V_{CC} = V_{CCO} = V_{CCX} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = 0°C$ to 70°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage			2		V_{CC} + 0.3	V
V_{IL}	Input Low Voltage			-0.3		0.8	V
I_{IH}	Input High Current	CLK_SEL, ODASEL_[1:0], ODBSEL_[1:0]	$V_{CC} = V_{IN} = 3.465V$			150	µA
		PDSEL_[2:0]	$V_{CC} = V_{IN} = 3.465V$			10	µA
I_{IL}	Input Low Current	CLK_SEL, ODASEL_[1:0], ODBSEL_[1:0]	$V_{CC} = 3.465V$, $V_{IN} = 0V$	-10			µA
		PDSEL_[2:0]	$V_{CC} = 3.465$, $V_{IN} = 0V$	-150			µA

Table 4C. Differential DC Characteristics, $V_{CC} = V_{CCO} = V_{CCX} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = 0°C$ to $70°C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
I_{IH}	Input High Current	CLK0, nCLK0, CLK1, nCLK1	$V_{CC} = V_{IN} = 3.465V$			150	µA
I_{IL}	Input Low Current	CLK0, CLK1	$V_{CC} = 3.465V$, $V_{IN} = 0V$	-10			µA
		nCLK0, nCLK1	$V_{CC} = 3.465V$, $V_{IN} = 0V$	-150			µA
V_{PP}	Peak-to-Peak Input Voltage			0.15		1.3	V
V_{CMR}	Common Mode Input Voltage; NOTE 1			V_{EE}		$V_{CC} – 0.85$	V

NOTE 1. Common mode voltage is defined at the crosspoint.

Table 4D. LVPECL DC Characteristics, $V_{CC} = V_{CCO} = V_{CCX} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = 0°C$ to $70°C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{OH}	Output High Voltage; NOTE 1		$V_{CCO} – 1.10$		$V_{CCO} – 0.75$	V
V_{OL}	Output Low Voltage; NOTE 1		$V_{CCO} – 2.0$		$V_{CCO} – 1.6$	V
V_{SWING}	Peak-to-Peak Output Voltage Swing		0.6		1.0	V

NOTE 1: Outputs terminated with 50Ω to $V_{CCO} – 2V$. See Parameter Measurement Information section, *3.3V Output Load Test Circuit.*

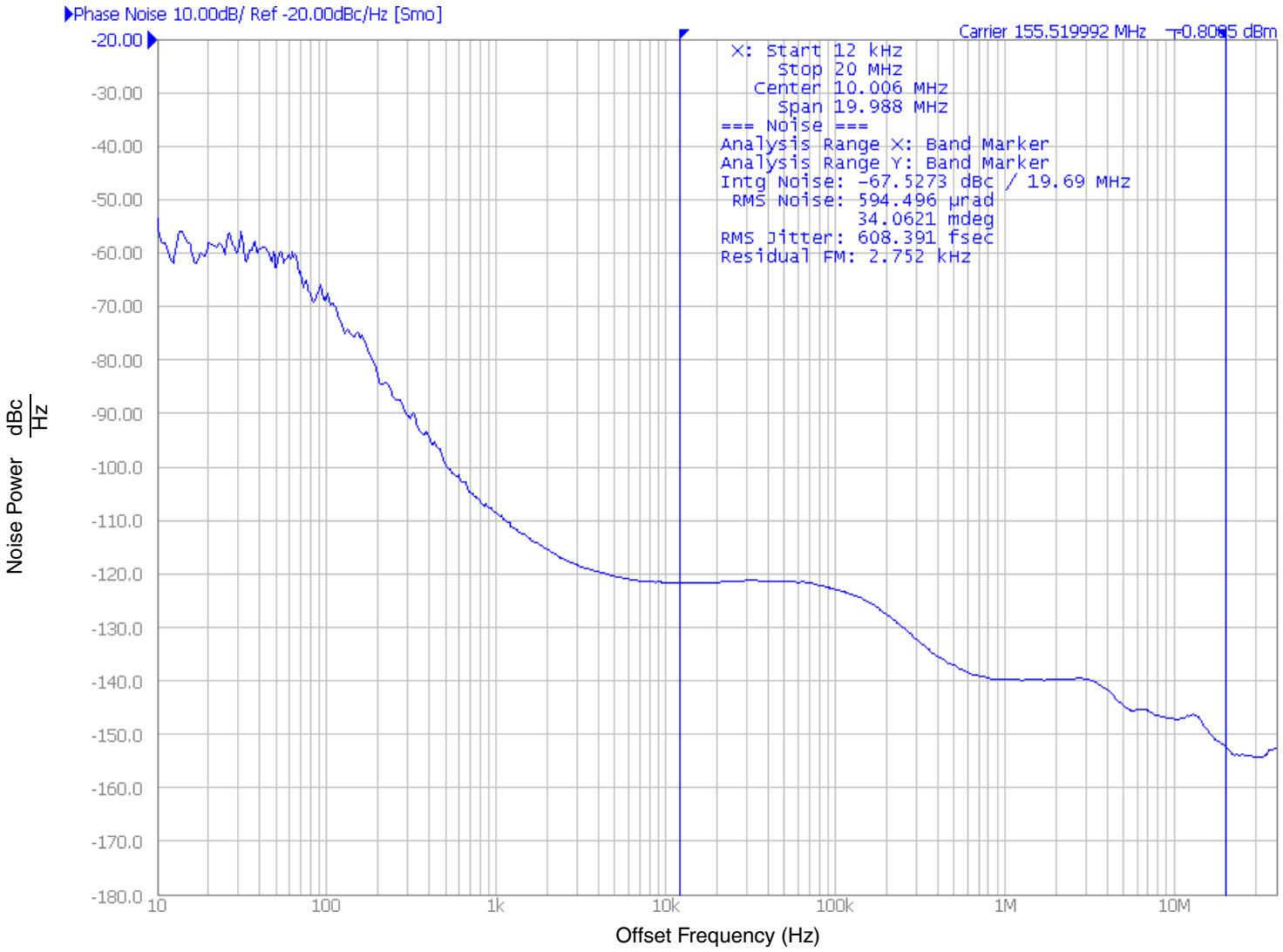
AC Electrical Characteristics

Table 5. AC Characteristics, $V_{CC} = V_{CCO} = V_{CCX} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = 0°C$ to $70°C$

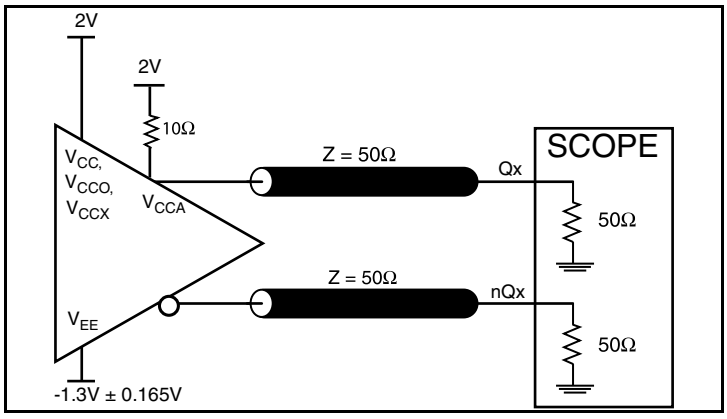
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{IN}	Input Frequency		0.008		156.25	MHz
f_{OUT}	Output Frequency		19.44		622.08	MHz
*t*jit(Ø)	RMS Phase Jitter, (Random), NOTE 1	77.76MHz f_{OUT}, 27MHz crystal, Integration Range: 12kHz – 20MHz		0.823	0.951	ps
		155.52MHz f_{OUT}, 27MHz crystal, Integration Range: 12kHz – 20MHz		0.674	0.788	ps
		622.08MHz f_{OUT}, 27MHz crystal, Integration Range: 12kHz – 20MHz		0.616	0.736	ps
*t*sk(o)	Output Skew; NOTE 2, 3				50	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	100		450	ps
odc	Output Duty Cycle		48		52	%
PSNR	Power Supply Noise Rejection; NOTE 4	VPP = 50mV Sine Wave, Integration Range: 10kHz - 10MHz		-95		dB
t_{LOCK}	Output-to-Input Phase Lock Time; NOTE 5	Reference Clock Input is ±50ppm from Nominal Frequency		3		s

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
NOTE: Characterized with outputs at the same frequency using the loop filter components for the 44Hz loop bandwidth.
Refer to Jitter Attenuator Loop Bandwidth Selection Table.
NOTE 1: Refer to the Phase Noise Plot.
NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the output differential crosspoints.
NOTE 4: PSNR results achieved by injecting noise on V_{CCA} supply pin with no external filter network.
NOTE 5: Lock Time measured from power-up to stable output frequency.

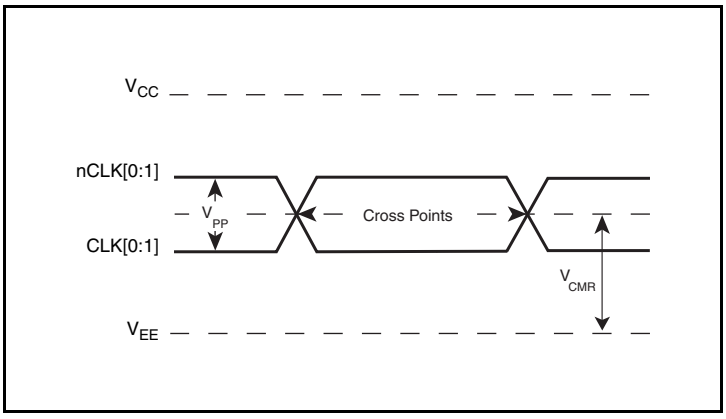
Typical Phase Noise at 155.52MHz



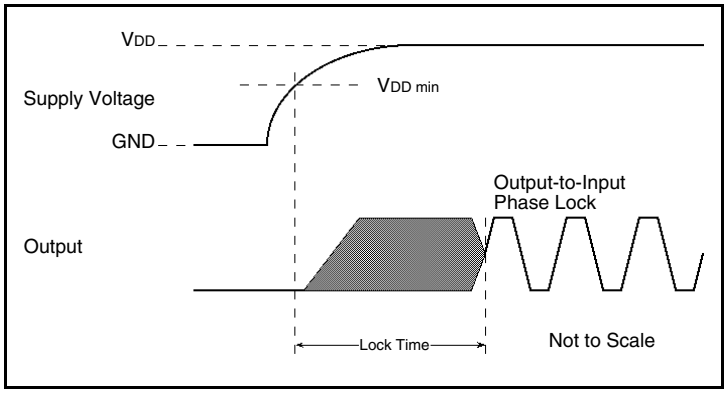
Parameter Measurement Information



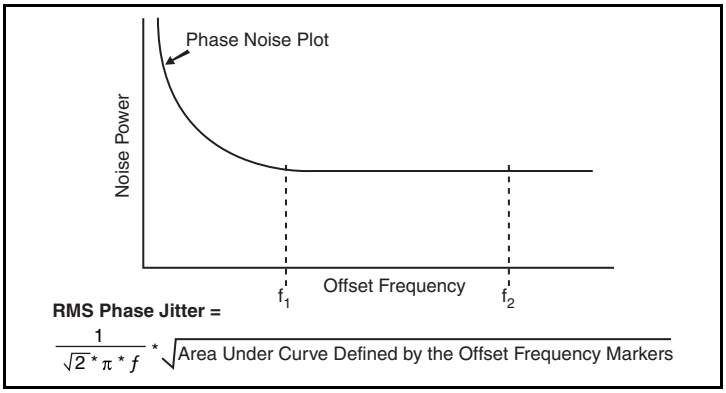
3.3V LVPECL Output Load AC Test Circuit



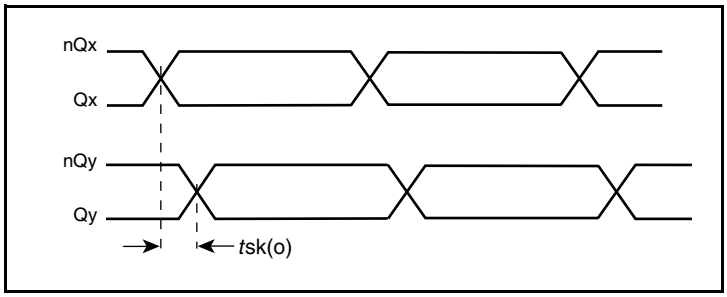
Differential Input Level



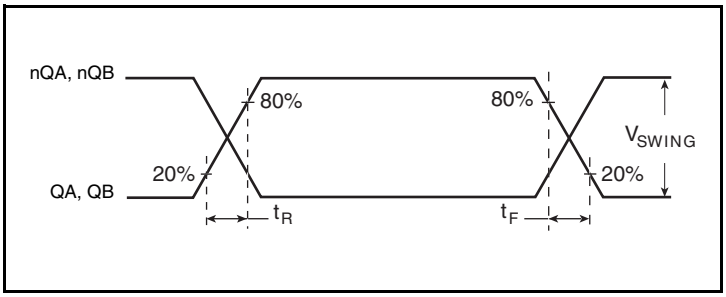
Output-to-Input Phase Lock Time



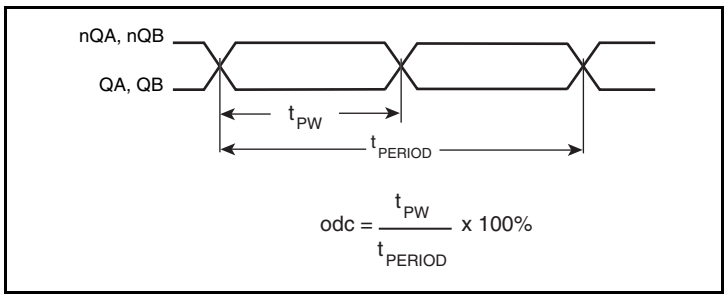
RMS Phase Jitter



Output Skew



LVPECL Output Rise/Fall Time



Output Duty Cycle/Pulse Width/Period

Applications Information

Wiring the Differential Input to Accept Single-Ended Levels

Figure 1 shows how a differential input can be wired to accept single ended levels. The reference voltage $V_1 = V_{CC}/2$ is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V_1 in the center of the input voltage swing. For example, if the input clock swing is 2.5V and V_{CC} = 3.3V, R1 and R2 value should be adjusted to set V_1 at 1.25V. The values below are for when both the single ended swing and V_{CC} are at the same voltage. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission line impedance. For most 50Ω applications, R3 and R4 can be 100Ω. The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVCMOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however V_{IL} cannot be less than -0.3V and V_{IH} cannot be more than V_{CC} + 0.3V. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

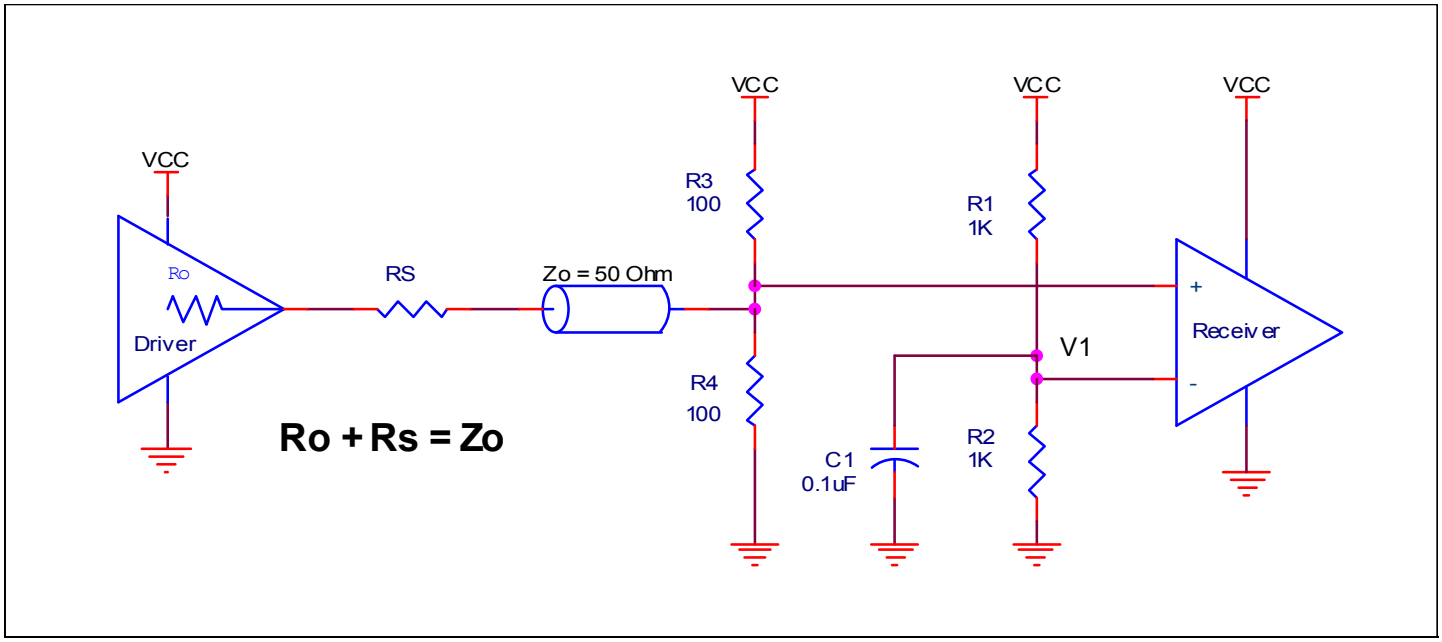


Figure 1. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

Differential Clock Input Interface

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, HCSL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. *Figures 2A to 2E* show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please consult with the vendor of the driver component to confirm the driver termination requirements. For example, in Figure 3A, the input termination applies for IDT open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

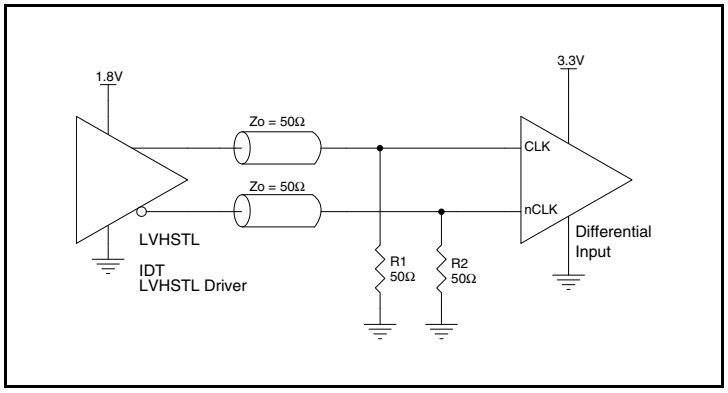


Figure 2A. CLK/nCLK Input Driven by an IDT Open Emitter LVHSTL Driver

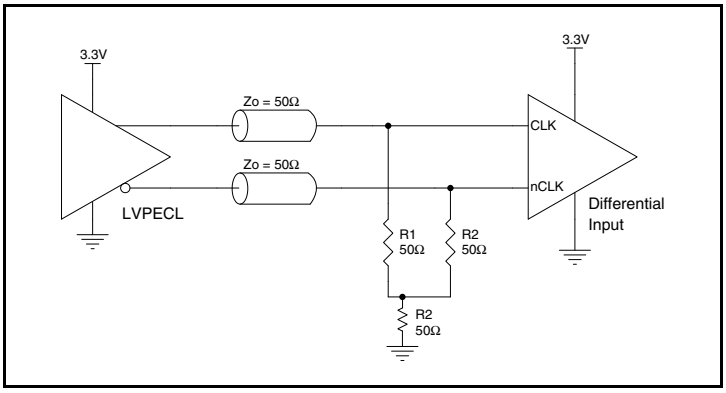


Figure 2B. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

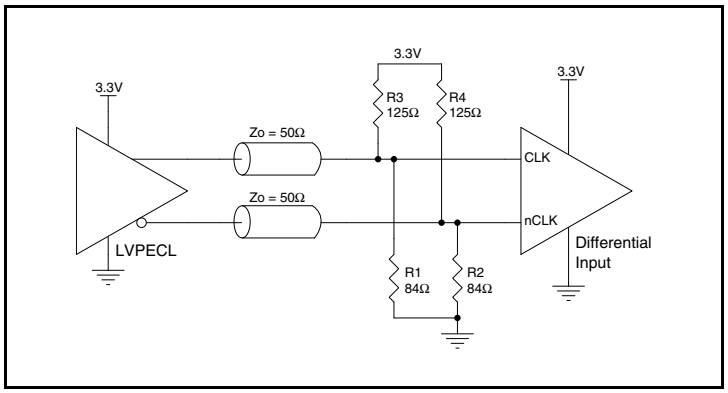


Figure 2C. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

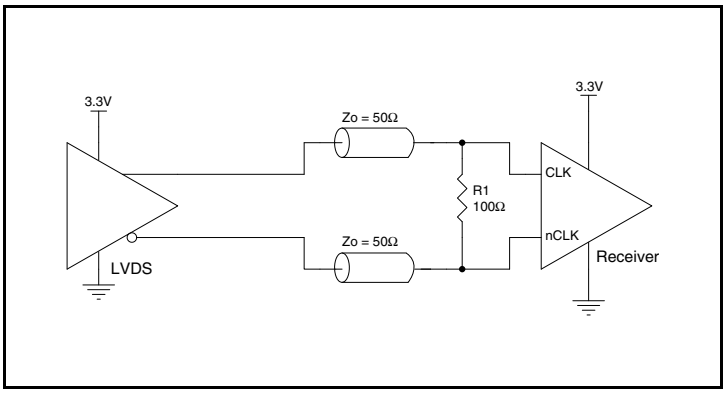


Figure 2D. CLK/nCLK Input Driven by a 3.3V LVDS Driver

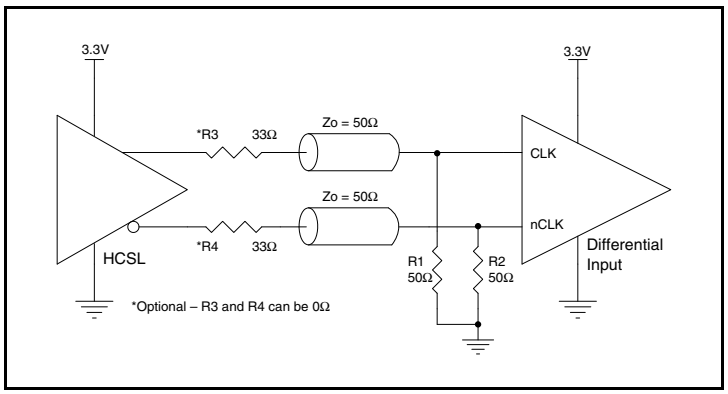


Figure 2E. CLK/nCLK Input Driven by a 3.3V HCSL Driver

Recommendations for Unused Input and Output Pins

Inputs:

CLK/nCLK Inputs

For applications not requiring the use of the differential input, both CLK and nCLK can be left floating. Though not required, but for additional protection, a 1kΩ resistor can be tied from CLK to ground.

LVCMOS Control Pins

All control pins have internal pullups or pulldowns; additional resistance is not required but can be added for additional protection. A 1kΩ resistor can be used.

Outputs:

LVPECL Outputs

All unused LVPECL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

Termination for 3.3V LVPECL Outputs

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

The differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive 50Ω transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 3A and 3B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

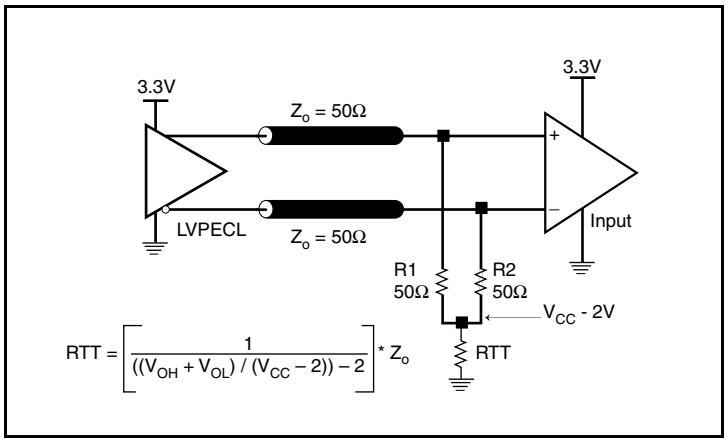


Figure 3A. 3.3V LVPECL Output Termination

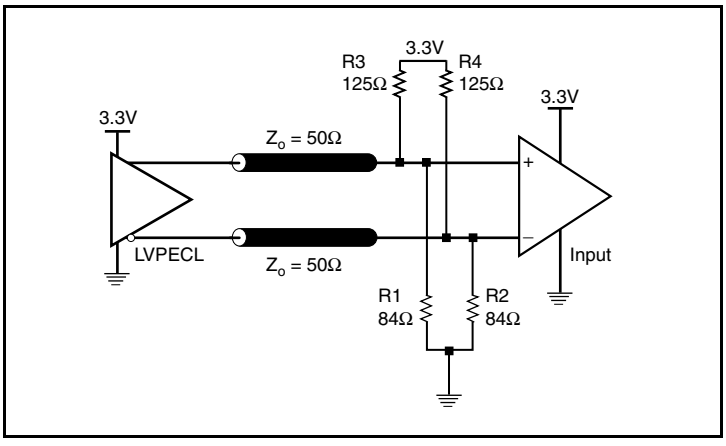


Figure 3B. 3.3V LVPECL Output Termination

Schematic Layout

Figure 4 (next page) shows an example of the ICS813N322I-02 application schematic. In this example, the device is operated at VCC=VCCA=VCCX=VCCO=3.3V. The inputs are driven by a 3.3V LVPECL driver and an LVDS driver. Two examples of PECL output terminations are shown in this schematic.

A three pole loop filter is used for the greater reduction of 8 or 10 kHz phase detector spurs relative to that afforded by a two pole loop filter. It is recommended that the loop filter components be laid out on the ICS813N322I-02 side of the PCB directly adjacent to the LF0 and LF1 pins.

As with any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The ICS813N322I-02 provides separate VCC, VCCA, VCCX and VCCO power supplies for each jitter attenuator to isolate any high switching noise from coupling into the internal PLLs.

In order to achieve the best possible filtering, it is highly recommended that the 0.1uF capacitors on the device side of the ferrite beads be placed on the device side of the PCB as close to the power pins as possible. This is represented by the placement of these capacitors in the schematic. If space is limited, the ferrite beads, 10uf and 0.1uF capacitor connected to 3.3V can be placed on the opposite side of the PCB. If space permits, place all filter components on the device side of the board.

Power supply filter recommendations are a general guideline to be used for reducing external noise from coupling into the devices. The filter performance is designed for a wide range of noise frequencies. This low-pass filter starts to attenuate noise at approximately 10 kHz. If a specific frequency noise component is known, such as switching power supplies frequencies, it is recommended that component values be adjusted and if required, additional filtering be added. Additionally, good general design practices for power plane voltage stability suggests adding bulk capacitance in the local area of all devices.

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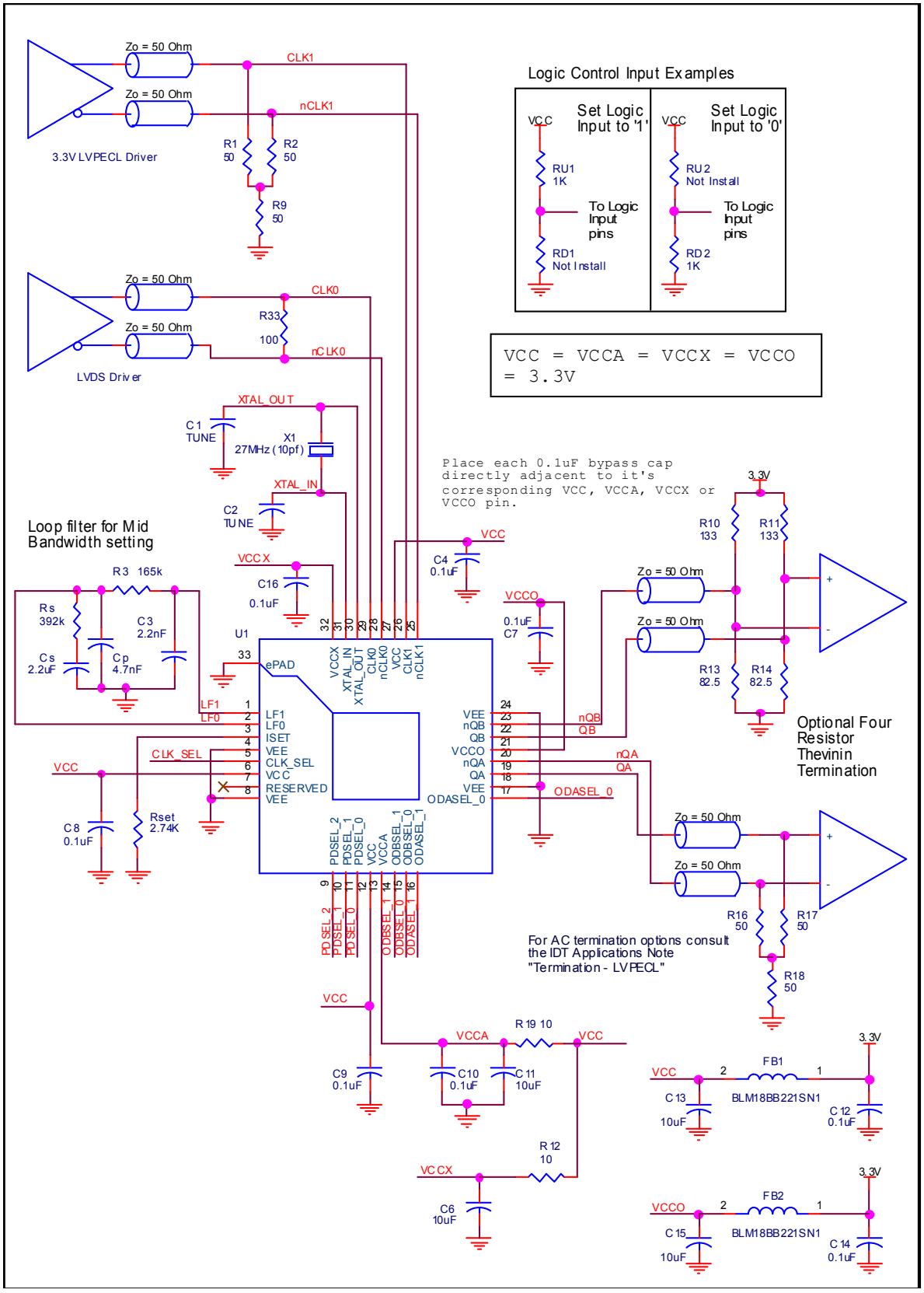
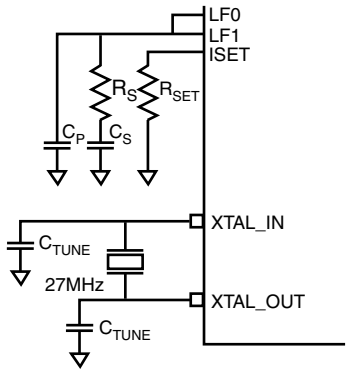


Figure 4. ICS813N322-02 Application Schematic

Jitter Attenuator External Components

Choosing the correct external components and having a proper printed circuit board (PCB) layout is a key task for quality operation of the Jitter Attenuator. In choosing a crystal, special precaution must be taken with load capacitance (C_L), frequency accuracy and temperature range.

The crystal's C_L characteristic determines its resonating frequency and is closely related to the center tuning of the crystal. The total external capacitance seen by the crystal when installed on a PCB is the sum of the stray board capacitance, IC package lead capacitance, internal device capacitance and any installed tuning capacitors (C_{TUNE}). The recommended C_L in the Crystal Parameter Table balances the tuning range by centering the tuning curve for a typical PCB. If the crystal C_L is greater than the total external capacitance, the crystal will oscillate at a higher frequency than the specification. If the crystal C_L is lower than the total external capacitance, the crystal will oscillate at a lower frequency than the specification. Tuning adjustments might be required depending on the PCB parasitics or if using a crystal with a higher C_L specification. In addition, the frequency accuracy specification in the crystal characteristics table are used to calculate the APR (Absolute Pull Range).



Crystal Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
	Mode of Oscillation			Fundamental		
f_N	Frequency			27		MHz
f_T	Frequency Tolerance				±20	ppm
f_S	Frequency Stability				±20	ppm
	Operating Temperature Range		-40		+85	^{0}C
C_L	Load Capacitance			10		pF
C_O	Shunt Capacitance			4		pF
ESR	Equivalent Series Resistance				40	Ω
	Aging @ 25 ^{0}C	First Year			±3	ppm

The VCXO-PLL Loop Bandwidth Selection Table shows R_S, C_S,C_P and R_{SET} values for recommended high, mid and low loop bandwidth configurations. The device has been characterized using these parameters. In addition, the digital VCXO gain (KVCXO) has been provided for additional loop filter requirements.

Jitter Attenuator Characteristics Table

Symbol	Parameter	Typical	Units
k_{VCXO}	VCXO Gain	2.78	kHz/V

Jitter Attenuator Loop Bandwidth Selection Table (2ND Order Loop Filter)

Bandwidth	Crystal Frequency	R_S (kΩ)	C_S (µF)	C_P (µF)	R3 (kΩ)	C3 (µF)	R_{SET} (kΩ)
15Hz (Low)	27MHz	215	10	0.022	0	DEPOP	2.74
30Hz (Mid)	27MHz	365	2.2	0.0047	0	DEPOP	2.74
60Hz (High)	27MHz	470	1	0.0022	0	DEPOP	1.5

NOTE: See Application schematic to identify loop filter components RS, CS, CP, R3, C3 and RSET.

For applications in which there is substantial low frequency jitter in the input reference and the phase detector frequency of 8kHz or 10kHz lies in or near a jitter mask, a three pole filter is recommended.

Suggested part values are in the table below. Note that the option of a three pole filter can be left open by laying out the three pole filter but setting R3 to 0 ohms and not populating C3. Refer to the application schematic for a specific example.

Jitter Attenuator Loop Bandwidth Selection Table (3RD Order Loop Filter)

Bandwidth	Crystal Frequency	R_S (kΩ)	C_S (µF)	C_P (µF)	R3 (kΩ)	C3 (µF)	R_{SET} (kΩ)
15Hz (Low)	27MHz	196	10	0.022	82.5	0.010	2.74
30Hz (Mid)	27MHz	392	2.2	0.0047	165	0.0022	2.74
60Hz (High)	27MHz	432	1	0.0022	182	0.001	1.5

NOTE: See Application schematic to identify loop filter components RS, CS, CP, R3, C3 and RSET.

The crystal and external loop filter components should be kept as close as possible to the device. Loop filter and crystal traces should be kept short and separated from each other. Other signal traces should be kept separate and not run underneath the device, loop filter or crystal components.

VFQFN EPAD Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 5.* The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as “heat pipes”. The number of vias (i.e. “heat pipes”) are application specific and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor’s Thermally/ Electrically Enhance Leadframe Base Package, Amkor Technology.

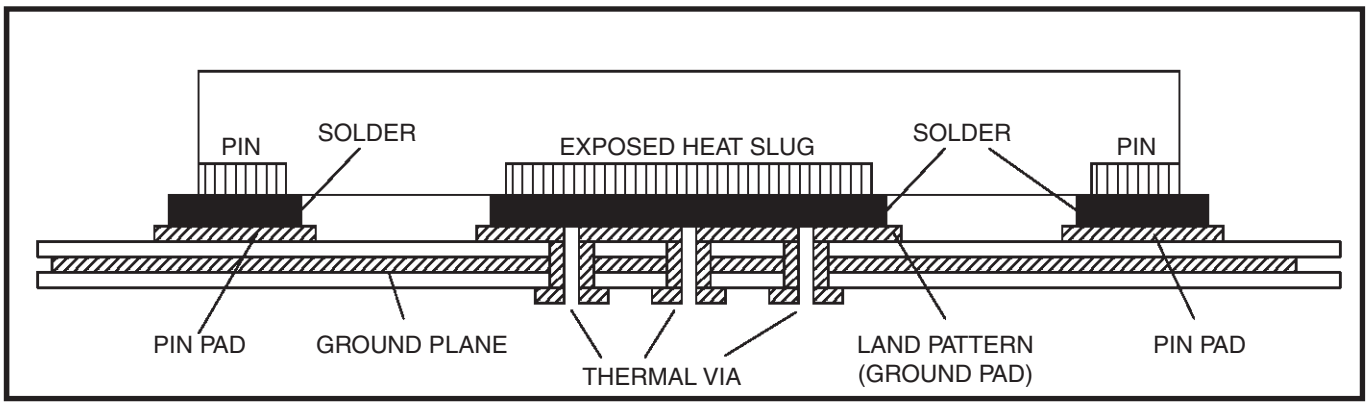


Figure 5. P.C. Assembly for Exposed Pad Thermal Release Path – Side View (drawing not to scale)

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS813N322-02.
Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS813N322-02 is the sum of the core power plus the power dissipated in the load(s).
The following is the power dissipation for V_{CCO} = 3.3V + 5% = 3.465V, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power $(core)_{MAX} = V_{CCO\_MAX} * I_{EE\_MAX}$ = 3.465V * 274mA = **949.41mW**
- Power $(outputs)_{MAX}$ = **31.55mW/Loaded Output pair**
  If all outputs are loaded, the total power is 2 * 31.55mW = **63.1mW**

Total Power$_{\_MAX}$ (3.465V, with all outputs switching) = 949.41mW + 63.1mW = **1012.51mW**

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, Tj, to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for Tj is as follows: $Tj = \theta_{JA} * Pd\_total + T_A$

Tj = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 33.1°C/W per Table 6 below.

Therefore, Tj for an ambient temperature of 70°C with all outputs switching is:

70°C + 1.013W * 33.1°C/W = 103.6°C. This is below the limit of 125°C.

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 32 Lead VFQFN, Forced Convection

θ_{JA} by Velocity			
Meters per Second	**0**	**1**	**2.5**
Multi-Layer PCB, JEDEC Standard Test Boards	33.1°C/W	28.1°C/W	25.4°C/W

3. Calculations and Equations.

The purpose of this section is to calculate the power dissipation for the LVPECL output pair.

LVPECL output driver circuit and termination are shown in *Figure 6.*

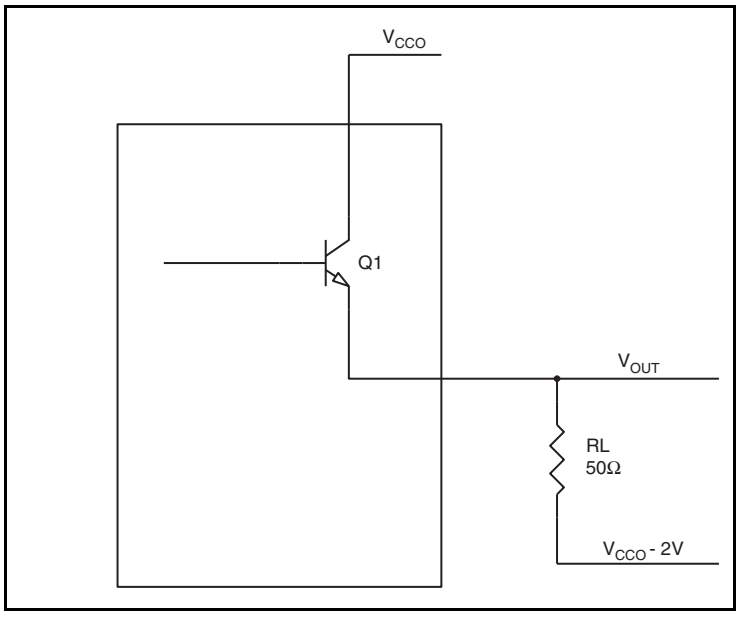


Figure 6. LVPECL Driver Circuit and Termination

To calculate power dissipation per output pair due to loading, use the following equations which assume a 50Ω load, and a termination voltage of V_{CCO} – 2V.

- For logic high, $V_{OUT} = V_{OH\_MAX} =$ **V_{CCO_MAX} – 0.75V**
  ($V_{CC\_MAX} – V_{OH\_MAX}$) = **0.75V**
- For logic low, $V_{OUT} = V_{OL\_MAX} =$ **V_{CCO_MAX} – 1.6V**
  ($V_{CC\_MAX} – V_{OL\_MAX}$) = **1.6V**

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$Pd\_H = [(V_{OH\_MAX} – (V_{CCO\_MAX} – 2V))/R_L] * (V_{CCO\_MAX} – V_{OH\_MAX}) = [(2V– (V_{CCO\_MAX} – V_{OH\_MAX}))/R_L] * (V_{CCO\_MAX} – V_{OH\_MAX}) =$
$[(2V– 0.75V)/50Ω] * 0.75V =$ **18.75mW**

$Pd\_L = [(V_{OL\_MAX} – (V_{CCO\_MAX} – 2V))/R_L] * (V_{CCO\_MAX} – V_{OL\_MAX}) = [(2V – (V_{CCO\_MAX} – V_{OL\_MAX}))/R_L] * (V_{CCO\_MAX} – V_{OL\_MAX}) =$
$[(2V – 1.6V)/50Ω] * 1.6V =$ **12.80mW**

Total Power Dissipation per output pair = Pd_H + Pd_L = **31.55mW**

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 32 Lead VFQFN

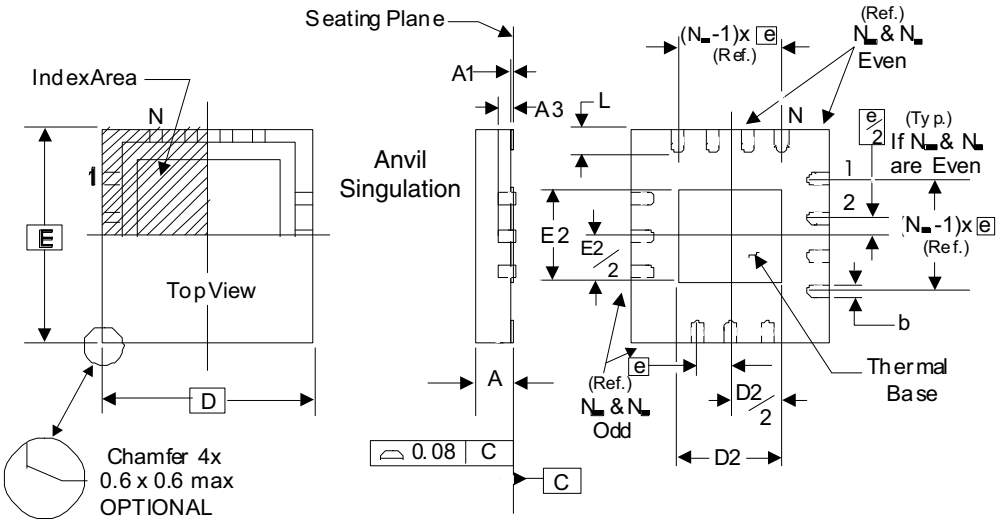
θ_{JA} vs. Air Flow			
Meters per Second	**0**	**1**	**2.5**
Multi-Layer PCB, JEDEC Standard Test Boards	33.1°C/W	28.1°C/W	25.4°C/W

Transistor Count

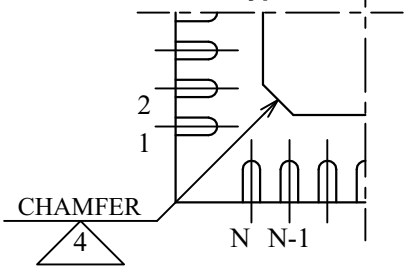
The transistor count for ICS813N322-02813N322-02 is: 44,795

Package Outline and Package Dimensions

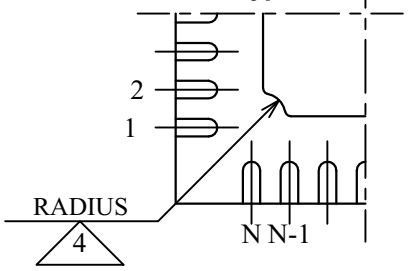
Package Outline - K Suffix for 32 Lead VFQFN



Bottom View w/Type A ID



Bottom View w/Type C ID



There are 2 methods of indicating pin 1 corner at the back of the VFQFN package are:

1. Type A: Chamfer on the paddle (near pin 1)
2. Type C: Mouse bite on the paddle (near pin 1)

Table 8. Package Dimensions

JEDEC Variation: VHHD-2/-4 All Dimensions in Millimeters			
Symbol	**Minimum**	**Nominal**	**Maximum**
N		32	
A	0.80		1.00
A1	0		0.05
A3		0.25 Ref.	
b	0.18	0.25	0.30
N_D & N_E			8
D & E		5.00 Basic	
D2 & E2	3.0		3.3
e		0.50 Basic	
L	0.30	0.40	0.50

Reference Document: JEDEC Publication 95, MO-220

NOTE: The following package mechanical drawing is a generic drawing that applies to any pin count VFQFN package. This drawing is not intended to convey the actual pin count or pin layout of this device. The pin count and pinout are shown on the front page. The package dimensions are in Table 8.

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
813N322CK-02LF	ICSN322C02L	“Lead-Free” 32 Lead VFQFN	Tray	0°C to 70°C
813N322CK-02LFT	ICSN322C02L	“Lead-Free” 32 Lead VFQFN	Tape & Reel	0°C to 70°C

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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

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